ESRF	Experiment title: Temperature dependence of latt single crystals (La ₃ Ga ₅ SiO ₁₄)	ice parameters of langasite	Experiment number : MA645		
Beamline:	Date of experiment:		Date of report:		
BM 20	from: 18/02/2009	to: 21/02/2009	15/12/2009		
Shifts: 9	Local contact(s): Dr. Nicole	Jeutter	Received at ESRF:		
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Report

16/12/2009

Temperature dependence of lattice parameters of langasite single crystals (La₃Ga₅SiO₁₄)

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Aims of the experimental and scientific background

Due to its outstanding piezoelectric properties, langasite (La₃Ga₅SiO₁₄) is a very suitable material for high-effective SAW filters in modern information and communication technology. Currently, it is possible to grow large langasite single crystals up to 3 inches in diameter [1,2]. Further potential applications using langasite single crystals are focused to pressure or temperature sensor devices operating at high temperatures up to 1200°C. The high-temperature applications presume that the langasite does not show any phase transformation before melting at about 1475°C. For the characterisation of the high temperature behaviour a precise knowledge of the thermal expansion is required.

Experimental method

Using the X-ray diffraction we measured the temperature dependence of the two significant lattice parameter a(T) and c(T) of the trigonale langasite single crystals belonging to crystallographic space group P321. With a specially prepared substrate orientation (Fig. 1, 2) it is possible to measure the two parameters a(T) and c(T) independently of each other and from the same single crystal area. The

asymmetric reflections (000 6) and (10 -1-1 0) are well suitable to determine the lattice parameters a and c, independently of each other. With the Bragg angle $\Theta_{(hkil)}(T)$ which has to be measured we have the relation:

(1) $\lambda = 2d_{(hkil)}(T) \cdot \sin(\Theta_{(hkil)}(T)) \rightarrow 2d_{(hkil)}(T) \rightarrow a(T)$ bzw. c(T)

The measurements were carried out using the new material research goniometer of the CRG¹ Beamline ROBL² located at the bending magnet BM20 of the ESRF³ in Grenoble. The goniometer was equipped with an evacuable high-temperature chamber, which permits in-plane and out-of-plane measurements because of its spherical beryllium dom. Temperatures up to 1400°C are attainable. All our measurements were realized with a X-ray wavelength $\lambda = 0.15407(5)$ nm.

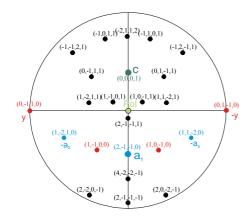


Fig. 1: Stereographic projection of the trigonal langasite. The pole and orientation is given by a temperature reduced influence surface. The four-indexing is used because of the threefold symmetry.

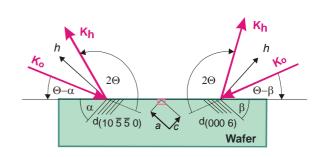
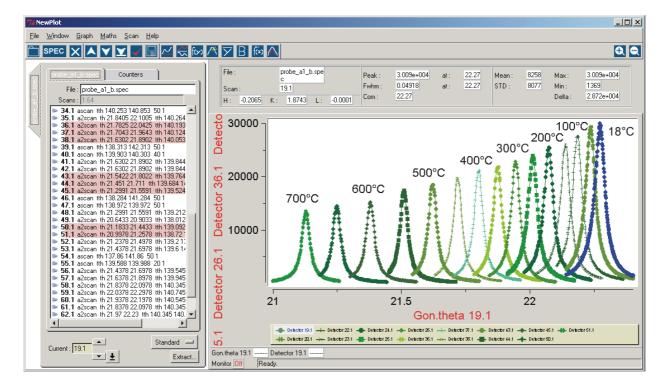


Fig. 2: Schematic for the X-ray diffraction measurement of a(T) and c(T) independently of each other and from the same single crystal area \Box . $\alpha + \beta = 90^{\circ}$.



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Fig. 3: X-ray diffraction rocking curves of the asymmetric (10-5-5 0)-reflection in dependence of the sample temperature. The decreasing of the intensity with the increasing of the temperature is to be due to the Debye-Waller factor.

Results

The lattice parameters a and c of the trigonal langasite single crystals determined from the measured Bragg angle $\Theta(T)$ are plotted against the temperature (Fig. 4 and 5). Their nonlinear behaviour can be described well with equations of second order.

It should be note that measurements at temperatures above 800°C could not be realized because the single crystal sample became instable regarding its shape.

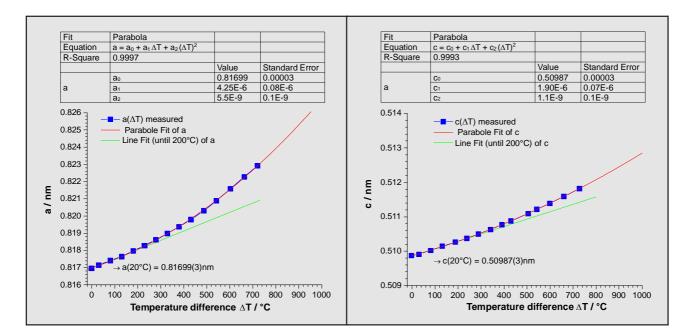


Fig. 4: The lattice parameter a and c of the langasite single crystals plotted against the temperature difference $\Delta T=T-20^{\circ}C$

For temperatures T expressed in °C, we have the following relation of the temperature-dependent lattice parameters a and c

(2)
$$a(T-20) = a_{20^{\circ}C} (1 + \alpha_{11}(T-20) + \beta_{11}(T-20)^2) c(T-20) = c_{20^{\circ}C} (1 + \alpha_{33}(T-20) + \beta_{33}(T-20)^2)$$

 α_{ii} , β_{ii} - linear and quadratic coefficient of thermal expansion, respectively $a_{20^{\circ}C}$, $c_{20^{\circ}}$ - lattice parameter *a* and *c* for 20^{\circ}C, respectively

The numeric values of the linear and quadratic thermal expansion coefficients obtained from the best fit are given in Table 1.

Thermal expansion of langasite single crystals (La ₃ Ga ₅ SiO ₁₄)				
lattice parameter at 20°C	$a_{20^{\circ}\mathrm{C}} = 0.81699(3)\mathrm{nm}$	$c_{20^{\circ}\text{C}} = 0.50987(3)\text{nm}$		
linear thermal expansion coefficient	$\alpha_{11} = 5.20(8) \cdot 10^{-6} \mathrm{K}^{-1}$	$\alpha_{33} = 3.72(8) \cdot 10^{-6} \mathrm{K}^{-1}$		
quadratic thermal expansion coefficient	$\beta_{11} = 6.7(1) \ 10^{-9} \mathrm{K}^{-2}$	$\beta_{33} = 1.1(1) \ 10^{-9} \text{K}^{-2}$		

Table 1: Parameter of the thermal expansion of langasite single crystals

We thank all members of the ROBL beamline team, especially Dr. C. Baehtz and Dr. N. Jeutter for all the helpful support during the time executing this experiment.

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